1. General description

Low V_{CEsat} PNP transistor and NPN Resistor- Equipped Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- Low V_{CEsat} and resistor-equipped transistor in one package
- Low threshold voltage (<1 V) compared to MOSFET
- · Low drive power required
- · Space-saving solution
- Reduction of component count
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Supply line switches
- · Battery charger switches
- · High-side switches for LEDs, drivers and backlights
- · Portable equipment

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Transistor '	TR1: PNP						
V _{CEO}	collector-emitter voltage	open base		-	-	-15	V
I _C	collector current			-	-	-500	mA
R _{CEsat}	collector-emitter saturation resistance	I_C = -500 mA; I_B = -50 mA; T_{amb} = 25 °C	[1]	-	300	500	mΩ
Transistor '	TR2: NPN						
V_{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
R1	bias resistor 1 (input)		[2]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[2]	8.0	1	1.2	

^[1] Pulse test: $t_p \le 300 \mu s$; $\delta \le 0.02$



^[2] See "Section 11: Test information" for resistor calculation and test conditions.

15 V 500 mA PNP/NPN loadswitch double transistor

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 I2 GND2
2	B1	base TR1	П6 П5 П4	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2		TR2
5	12	input (base) TR2	H ₁ H ₂ H ₃	TR1
6	C1	collector TR1	TSSOP6 (SOT363)	E1 B1 O2 sym036

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBLS1504Y-Q		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBLS1504Y-Q	%C4

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Transistor '	TR1: PNP					
V _{CBO}	collector-base voltage	open emitter		-	-15	V
V _{CEO}	collector-emitter voltage	open base		-	-15	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-500	mA
I _{CM}	peak collector current	t_p ≤ 1 ms; δ ≤ 0.02		-	-1	Α
I _B	base current			-	-50	mA
I _{BM}	peak base current	t_p ≤ 1 ms; δ ≤ 0.02		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Transistor '	TR2: NPN		,			
V _{CBO}	collector-base voltage	open emitter		-	50	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	10	V
V _I	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
I _{CM}	peak collector current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device			•			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C		-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

9. Thermal characteristics

Table 6. Thermal characteristics

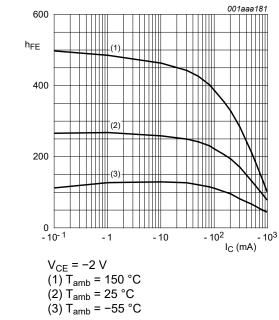
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

[1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

10. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Transistor	TR1: PNP				, .		
I _{CBO}	collector-base cut-off	V _{CB} = -15 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
020	current	V _{CB} = -15 V; I _E = 0 A; T _i = 150 °C		-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V _{CE} = -15 V; V _{BE} = 0 V; T _{amb} = 25 °C		-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I_{C} = -10 mA; T_{amb} = 25 °C		200	-	-	
		V _{CE} = -2 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	150	-	-	
		V_{CE} = -2 V; I_{C} = -500 mA; T_{amb} = 25 °C	[1]	90	-	-	
V _{CEsat}	collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-25	mV
	saturation voltage	I _C = -200 mA; I _B = -10 mA; T _{amb} = 25 °C		-	-	-150	mV
		I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	[1]	-	-	-250	mV
R _{CEsat}	collector-emitter saturation resistance		[1]	-	300	500	mΩ
V _{BEsat}	base-emitter saturation voltage		[1]	-	-	-1.1	V
V _{BEon}	base-emitter turn-on voltage	V _{CE} = -2 V; I _C = -100 mA; T _{amb} = 25 °C	[1]	-	-	-0.9	V
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	10	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C		100	280	-	MHz
Transistor	TR2: NPN						
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μA
	current	V _{CE} = 30 V; I _B = 0 A; T _i = 150 °C		-	-	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	180	μA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		60	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.5 mA; T _{amb} = 25 °C		-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 5 mA; T _{amb} = 25 °C		2.5	1.7	-	V
R1	bias resistor 1 (input)		[2]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[2]	0.8	1	1.2	
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	1	-	-	2.5	pF

Pulse test: $t_p \le 300~\mu s; \, \delta \le 0.02$ See "Section 11: Test information" for resistor calculation and test conditions.

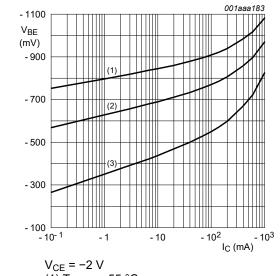


$$V_{CE} = -2 V$$
(1) $T_{cmb} = 150 \,^{\circ}C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

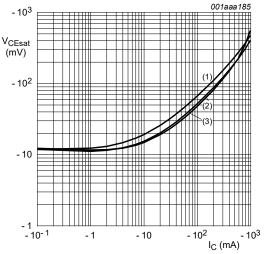
TR1 (PNP): DC current gain as a function of Fig. 1. collector current; typical values



(1) $T_{amb} = -55$ °C (2) T_{amb} = 25 °C

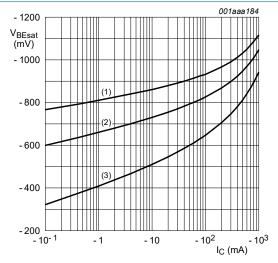
(3) $T_{amb} = 150 \, ^{\circ}C$

Fig. 3. TR1 (PNP): Base-emitter voltage as a function of collector current; typical values



 $I_{C}/I_{B} = 20$ (1) $T_{amb} = 150 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = -55 \,^{\circ}C$

Fig. 2. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B}=20$

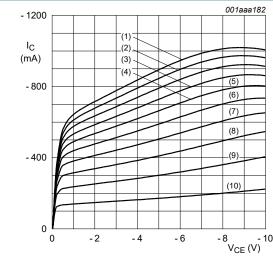
(1) T_{amb} = 150 °C

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 4. TR1 (PNP): Base-emitter saturation voltage as a function of collector current; typical values

15 V 500 mA PNP/NPN loadswitch double transistor



 T_{amb} = 25 °C

(1) $I_B = -7.0 \text{ mA}$

 $(2) I_B = -6.3 \text{ mA}$

 $(3) I_B = -5.6 \text{ mA}$

(4) $I_B = -4.9 \text{ mA}$ (5) $I_B = -4.2 \text{ mA}$

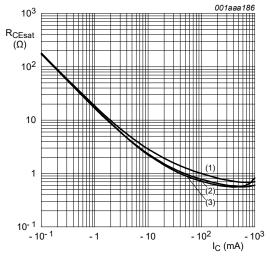
 $(6) I_B = -3.5 \text{ mA}$

 $(7) I_B = -2.8 \text{ mA}$

 $(8) I_B = -2.1 \text{ mA}$

 $(9) I_B = -1.4 \text{ mA}$

 $(10) I_B = -0.7 \text{ mA}$



 $I_C/I_B = 20$

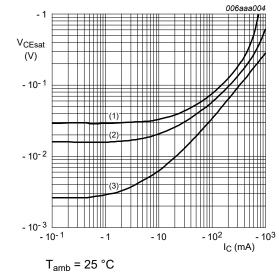
 $(1) T_{amb} = -55 °C$

(2) T_{amb}= 25 °C

(3) $T_{amb} = 150 \, ^{\circ}C$

Fig. 6. TR1 (PNP): Equivalent on-resistance as a function of collector current; typical values



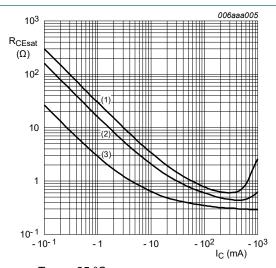


 $I_{amb} - 25 C$ (1) $I_C/I_B = 100$

(2) $I_C/I_B = 50$

(3) $I_C/I_B = 10$

Fig. 7. TR1 (PNP): Collector-emitter saturation voltage as a function of collector current; typical values

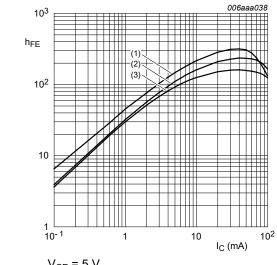


 $T_{amb} = 25 \,^{\circ}\text{C}$ (1) $I_{C}/I_{B} = 100$

(2) $I_C/I_B = 50$ (3) $I_C/I_B = 10$

Fig. 8. TR1 (PNP): Equivalent on-resistance as a function of collector current; typical values

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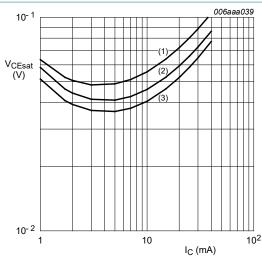
 $V_{CE} = 5 V$

 $(1) T_{amb} = 150 °C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 9. TR2 (NPN): DC current gain as a function of collector current; typical values

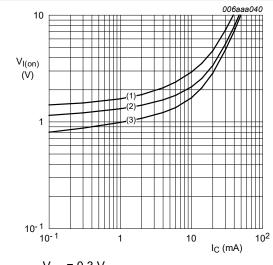


 $I_C/I_B = 20$

(1) $T_{amb} = 100 \, ^{\circ}C$ (2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 10. TR2 (NPN): Collector-emitter saturation voltage as a function of collector current; typical values



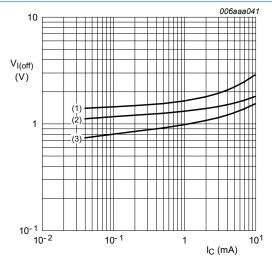
 $V_{CE} = 0.3 V$

(1) T_{amb} = - 40 °C

(2) T_{amb} = 25 °C

(3) T_{amb} = 100 °C

of collector current; typical values



 $V_{CE} = 5 V$

(1) $T_{amb} = -40 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 11. TR2 (NPN): On-state input voltage as a function | Fig. 12. TR2 (NPN): Off-state input voltage as a function of collector current; typical values

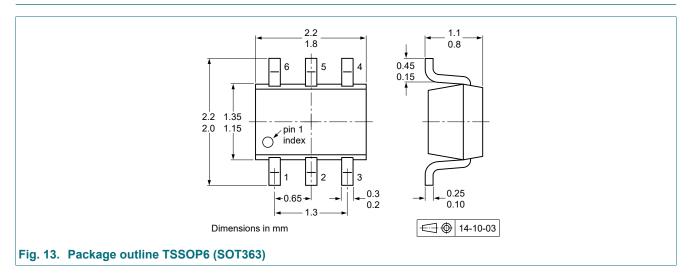
11. Test information

Quality information

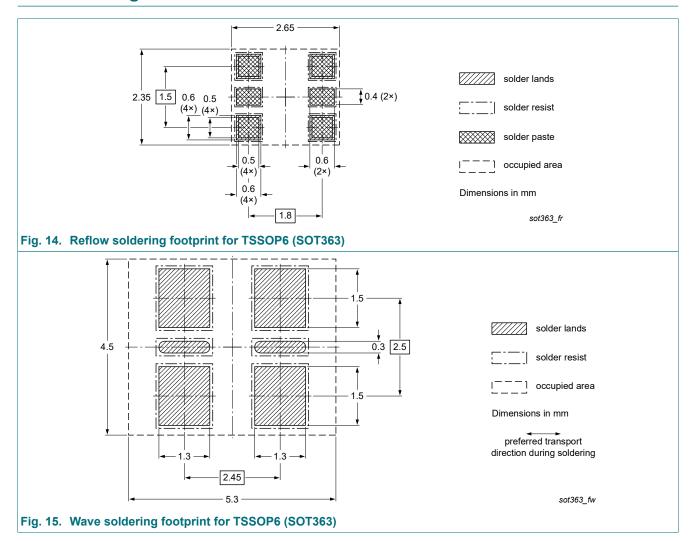
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline



13. Soldering



15 V 500 mA PNP/NPN loadswitch double transistor

14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBLS1504Y-Q v.1	20230601	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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